**Product data sheet** 

# 1. General description

Unidirectional ElectroStatic Discharge (ESD) protection diode in a flat lead very small SOD323F Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

### 2. Features and benefits

- ESD protection of one line
- ESD protection up to 30 kV
- IEC 61000-4-5; (surge); I<sub>PPM</sub> = 2.5 A
- Rated peak pulse power: P<sub>PPM</sub> = 150 W
- Ultra low leakage current: I<sub>RM</sub> < 1 nA</li>
- AEC-Q101 qualified

# 3. Applications

- computers and peripherals
- audio and video equipment
- cellular handsets and accessories
- portable electronics
- communication systems

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RWM</sub>	reverse standoff voltage	T <sub>amb</sub> = 25 °C	-	-	36	V
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}$ ; $V_R = 0 \text{ V}$ ; $T_{amb} = 25 \text{ °C}$	-	18	30	pF





# 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	1 2	1 + 2
2	Α	anode	SOD323F	sym035

<sup>[1]</sup> The marking bar indicates the cathode.

# 6. Ordering information

### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PESD36VS1UJ	SOD323F	plastic surface-mounted package; 2 leads	SOD323F			

# 7. Marking

## Table 4. Marking codes

Type number	Marking code
PESD36VS1UJ	BG

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
P <sub>PPM</sub>	peak pulse power	t <sub>p</sub> = 8/20 μs	[1][2]	-	150	W
I <sub>PPM</sub>	peak pulse current		[1][2]	-	2.5	Α
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
ESD maximu	m ratings					
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[2][3]	-	30	kV
		IEC 61000-4-2; air discharge	[2]	-	30	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses (8/20 μs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

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<sup>[2]</sup> Measured from pin 1 to pin 2.

<sup>[3]</sup> Device stressed with ten non-repetitive ESD pulses.

### **Unidirectional ESD protection diode**

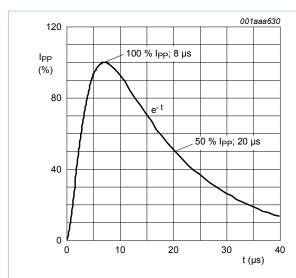


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

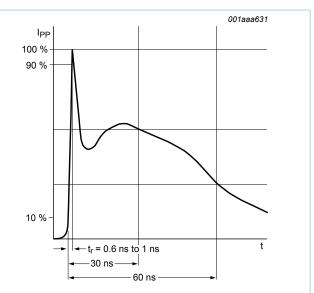


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage	T <sub>amb</sub> = 25 °C		-	-	36	V
I <sub>RM</sub>	reverse leakage current	V <sub>RWM</sub> = 36 V; T <sub>amb</sub> = 25 °C		-	1	10	nA
$V_{BR}$	breakdown voltage	I <sub>R</sub> = 2 mA; T <sub>amb</sub> = 25 °C		38.2	39	39.8	V
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; T <sub>amb</sub> = 25 °C		-	18	30	pF
V <sub>CL</sub>	clamping voltage	I <sub>PP</sub> = 1 A; T <sub>amb</sub> = 25 °C	[1][2]	-	-	58	V
		I <sub>PPM</sub> = 2.5 A; T <sub>amb</sub> = 25 °C	[1][2]	-	-	80	V
R <sub>dyn</sub>	dynamic resistance	T <sub>amb</sub> = 25 °C	[3]	-	9.5	-	Ω

<sup>[1]</sup> Device stressed with 8/20 μs exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

<sup>[2]</sup> Measured from pin 1 to pin 2.

<sup>[3]</sup> Non-repetitive current pulse, Transmission Line Pulse (TLP); square pulse; ANSI / ESD STM5.5.1-2008.

### **Unidirectional ESD protection diode**

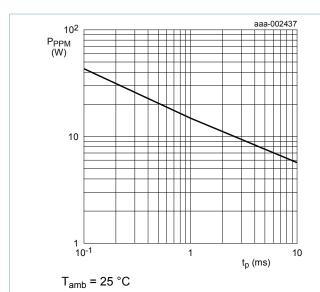


Fig. 3. Rated peak pulse power as a function of square pulse duration; maximum values

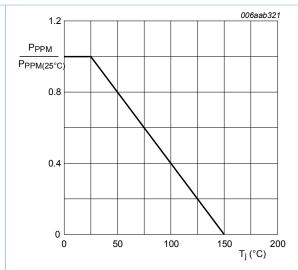


Fig. 4. Relative variation of rated peak pulse power as a function of junction temperature; typical values

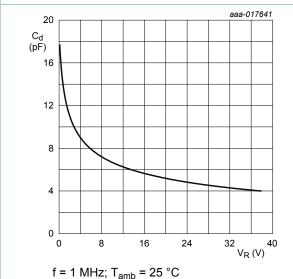


Fig. 5. Diode capacitance as a function of reverse voltage; typical values

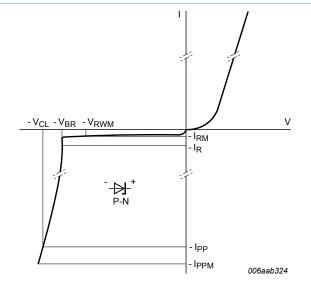
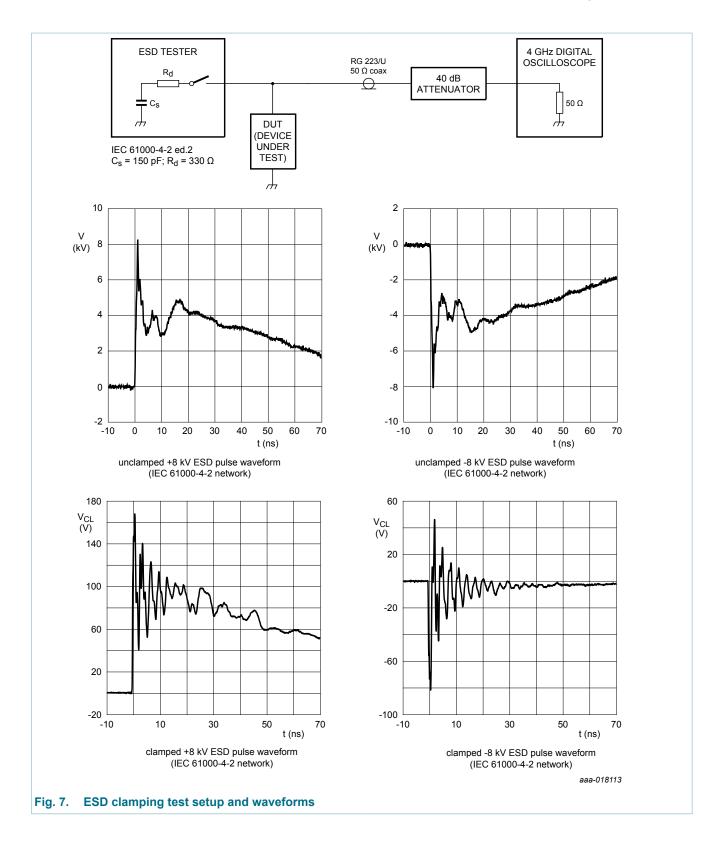


Fig. 6. V-I characteristics for a unidirectional ESD protection diode

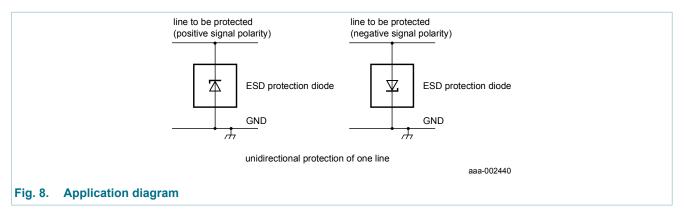
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### **Unidirectional ESD protection diode**



# 10. Application information

The device is designed for the protection of one unidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are either positive or negative with respect to ground. The device provides a surge capability of 150 W for an  $8/20~\mu s$  waveform.



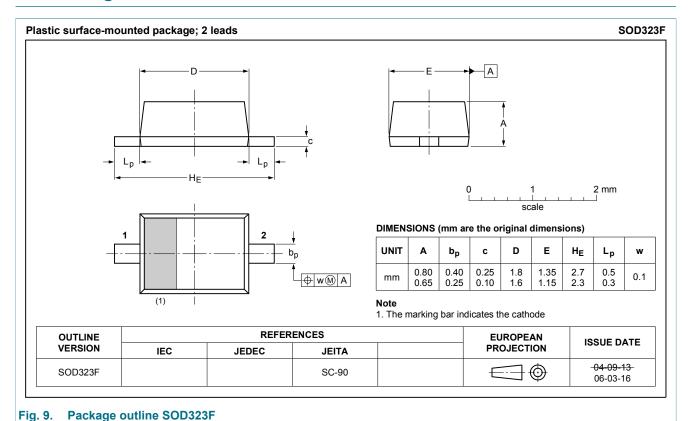
#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

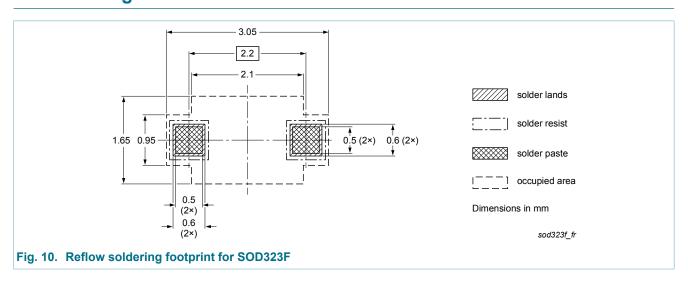
**Unidirectional ESD protection diode** 

# 11. Package outline



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# 12. Soldering



# 13. Revision history

### Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD36VS1UJ v.1	20150916	Product data sheet	-	-

# 14. Legal information

#### 14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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